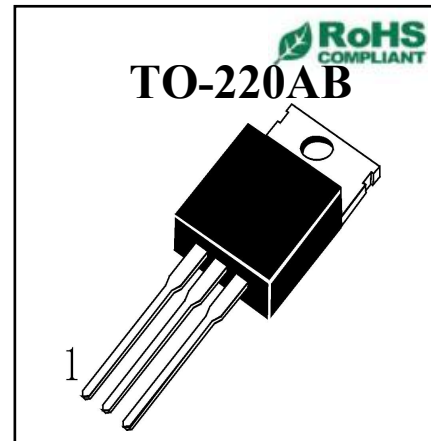


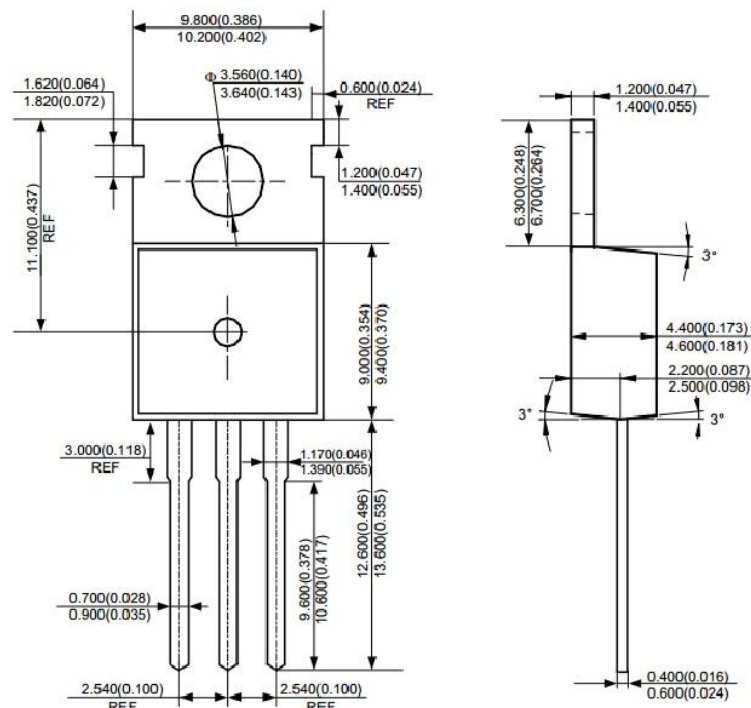
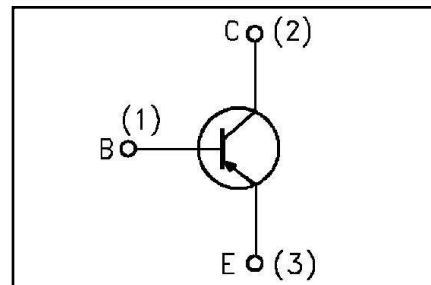
◆ Features:

- ✧ High efficiency, low deviation
高效率，低偏差
- ✧ Small input impedance, low consumption of power
输入阻抗小，功耗低
- ✧ Resistant of high temperature, high humidity
抗高温、高湿
- ✧ Good stability, reliability
稳定性好，可靠性高



◆ Applications

- ✧ Audio amplifier
音频放大器
- ✧ Switching applications
开关应用
- ✧ Complement to Type TIP41C(NPN)
与 TIP41C 互补应用
- ✧ Recommend for 100W high fidelity audio frequency amplifier output stage applications
推荐用于 65W 高保真音频放大器输出级应用



◆ Absolute Maximum Ratings (Tc=25°C)

Symbo l	Parameters	Ratings	Unit
VCBO	Collector-Base Voltage 集电极 - 基极电压	-100	V
VCEO	Collector-Emitter Voltage 集电极 - 发射极电压	-100	V
VEBO	Emitter-Base Voltage 发射极 - 基极电压	-7	V
I _C	Collector Current-Continuous 集电极连续电流	-6	A
I _B	Base Current-Continuous 基极连续电流	-1	A
PC	Collector Power Dissipation 耗散功率	65	W
T _j	Max.Operating junction temperature 最大结温	150	°C
T _{stg}	Storage Temperature 存储温度	-65 ~ +150	°C

◆ Electrical characteristics (Tc=25°C unless otherwise noted)

Symbol	Parameters	Min	Typ	Max	Units	Conditions
I _{CBO}	Collector Cutoff Current 集电极截止电流	--	--	-1	uA	V _{CE} =-100V, V _{EB} =0
I _{EBO}	Emitter Cutoff Current 发射极截止电流	--	--	-1.0	uA	V _{BE} =-10V, I _C =0
BV _{CEO}	Collector Emitter Sustaining voltage(Note 1) 集电极发射极持续电压	-100	--	--	V	I _C =-30mA, I _B =0
V _{CE(sat)}	Collector Emitter Saturation Voltage(Note 1) 集电极发射极饱和电压	--	--	-1.5	V	I _C =-4A, I _B =-0.4A
h _{FE}	DC Current Gain(Note 1) 直流电流增益	80	--	160		I _C =-1A, V _{CE} =-5V
f _T	Current-Gain—Bandwidth 电流增益带宽	10.0	--	--	MHz	V _{CE} =-10V, I _C =-0.5A, f=1MHz

Note 1: Pulse test: PW ≤ 300us , duty cycle ≤ 2%.